

## INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## **IRFS7434**

#### • FEATURES

- With TO-263( D2PAK ) packaging
- · High speed switching
- · Low gate input resistance
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

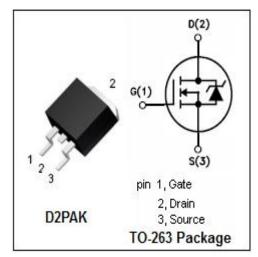
#### · Power supply

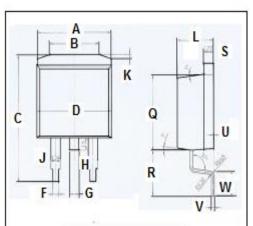
Switching applications

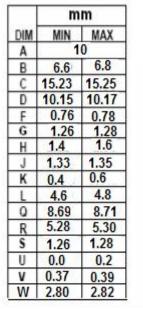
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	40	V		
V <sub>GSS</sub>	Gate-Source Voltage	±20	V		
ID	Drain Current-Continuous;Tc=25℃ Tc=100℃	320 226	A		
I <sub>DM</sub>	Drain Current-Single Pulsed	1270	А		
P <sub>D</sub>	Total Dissipation	294	W		
Tj	Operating Junction Temperature	175	°C		
T <sub>stg</sub>	Storage Temperature	-55~175	°C		

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.6	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	







#### isc website: www.iscsemi.cn

### isc & iscsemi is registered trademark

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### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	40			v
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.2		3.9	v
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =100A		1.25	1.6	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0V;Tc=25℃ V <sub>DS</sub> =40V; V <sub>GS</sub> = 0V; Tc=150℃			1 150	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =100A, V <sub>GS</sub> = 0 V		0.9	1.3	V

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